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September 1983 Revised May 2005

MM74HC540 • MM74HC541 Inverting Octal 3-STATE Buffer • Octal 3-STATE Buffer

General Description

The MM74HC540 and MM74HC541 3-STATE buffers utilize advanced silicon-gate CMOS technology. They possess high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits achieve speeds comparable to low power Schottky devices, while retaining the advantage of CMOS circuitry, i.e., high noise immunity, and low power consumption. Both devices have a fanout of 15 LS-TTL equivalent inputs.

The MM74HC540 is an inverting buffer and the MM74HC541 is a non-inverting buffer. The 3-STATE control gate operates as a two-input NOR such that if either G1 or G2 are HIGH, all eight outputs are in the high-impedance state

In order to enhance PC board layout, the MM74HC540 and MM74HC541 offers a pinout having inputs and outputs on opposite sides of the package. All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Features

- Typical propagation delay: 12 ns
- 3-STATE outputs for connection to system buses
- Wide power supply range: 2-6V
- Low quiescent current: 80 µA maximum (74HC Series)
- Output current: 6 mA

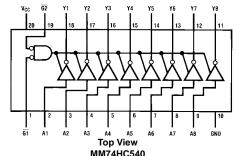
Ordering Code:

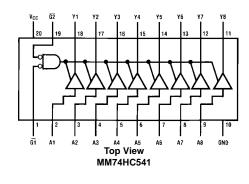
Order Number	Package Number	Package Description			
MM74HC540WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide			
MM74HC540SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide			
MM74HC540MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			
MM74HC540N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			
MM74HC541WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide			
MM74HC541SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide			
MM74HC541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			
MM74HC541N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams

Pin Assignments for DIP, SOIC, SOP and TSSOP





Absolute Maximum Ratings(Note 1)

(Note 2)

(Note 2)	
Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	-1.5 to V_{CC} +1.5V
DC Output Voltage (V _{OUT})	-0.5 to V_{CC} +0.5V
Clamp Diode Current (I _{CD})	±20 mA
DC Output Current, per pin (I _{OUT})	±35 mA
DC V _{CC} or GND Current,	
per pin (I _{CC})	±70 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T _L)	

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
DC Input or Output Voltage			
(V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	-40	+85	°C
Input Rise or Fall Times			
$(t_r, t_f) V_{CC} = 2.0V$		1000	ns
V _{CC} = 4.5V		500	ns
$V_{CC} = 6.0V$		400	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: –

Note 3: Power Dissipation temperature derating — plastic "N" packa 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

(Soldering 10 seconds)

Symbol	Parameter	Conditions	v _{cc}	T _A = 25°C		$T_A = -40 \text{ to } 85^{\circ}\text{C}$	T _A = -55 to 125°C	Units	
Зуппоог				Тур		Guaranteed L	Units		
V _{IH}	Minimum HIGH Level		2.0V		1.5	1.5	1.5	V	
	Input Voltage		4.5V		3.15	3.15	3.15	V	
			6.0V		4.2	4.2	4.2	V	
V _{IL}	Maximum LOW Level		2.0V		0.5	0.5	0.5	V	
	Input Voltage		4.5V		1.35	1.35	1.35	V	
			6.0V		1.8	1.8	1.8	V	
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IH}$ or V_{IL}							
	Output Voltage	$ I_{OUT} \leq 20~\mu A$	2.0V	2.0	1.9	1.9	1.9	V	
			4.5V	4.5	4.4	4.4	4.4	V	
			6.0V	6.0	5.9	5.9	5.9	V	
		$V_{IN} = V_{IH}$ or V_{IL}							
		$ I_{OUT} \leq 6.0 \ mA$	4.5V	4.2	3.98	3.84	3.7	V	
		$ I_{OUT} \leq 7.8 \ mA$	6.0V	5.7	5.48	5.34	5.2	V	
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH}$ or V_{IL}							
	Output Voltage	$ I_{OUT} \leq 20~\mu A$	2.0V	0	0.1	0.1	0.1	V	
			4.5V	0	0.1	0.1	0.1	V	
			6.0V	0	0.1	0.1	0.1	V	
		$V_{IN} = V_{IH}$ or V_{IL}							
		$ I_{OUT} \leq 6.0 \ mA$	4.5V	0.2	0.26	0.33	0.4	V	
		$ I_{OUT} \leq 7.8 \ mA$	6.0V	0.2	0.26	0.33	0.4	V	
I _{IN}	Maximum Input	V _{IN} = V _{CC} or GND	6.0V		±0.1	±1.0	±1.0	μА	
	Current								
l _{OZ}	Maximum 3-STATE	$V_{IN} = V_{IH}$ or V_{IL} , $\overline{G} = V_{IH}$	6.0V		±0.5	±5	±10	μА	
	Output Leakage	V _{OUT} = V _{CC} or GND							
	Current								
I _{CC}	Maximum Quiescent	V _{IN} = V _{CC} or GND	6.0V		8.0	80	160	μА	
	Supply Current	$I_{OUT} = 0 \mu A$							

260°C

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH} , and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5V$ and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

 $V_{CC} = 5V, T_A = 25^{\circ}C, t_r = t_f = 6 \text{ ns}$

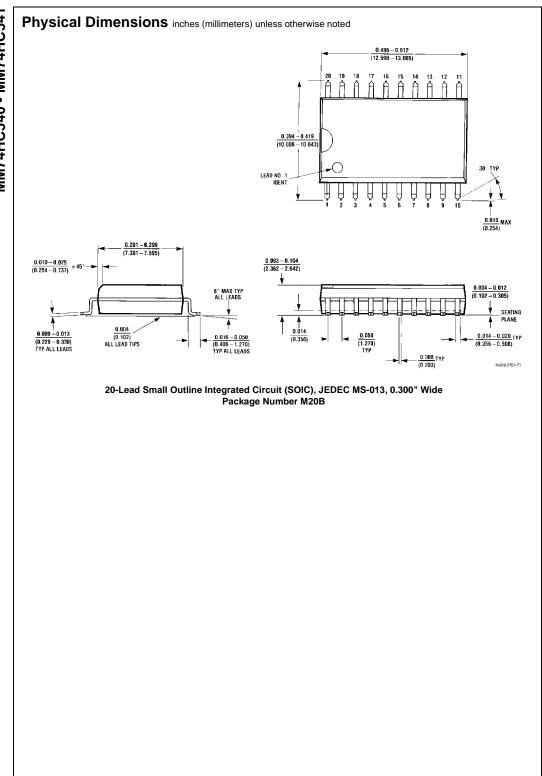
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t _{PHL} , t _{PLH}	Maximum Propagation	C _L = 45 pF	12	18	ns
	Delay (540)				
t _{PHL} , t _{PLH}	Maximum Propagation	C _L = 45 pF	14	20	ns
	Delay (541)				
t _{PZH} , t _{PZL}	Maximum Output Enable	$R_L = 1 \text{ k}\Omega$ $C_L = 45 \text{ pF}$	17	28	ns
	Time	$C_L = 45 \text{ pF}$			
t _{PHZ} , t _{PLZ}	Maximum Output Disable	$R_L = 1 \text{ k}\Omega$ $C_L = 5 \text{ pF}$	15	25	ns
	Time	$C_L = 5 pF$			

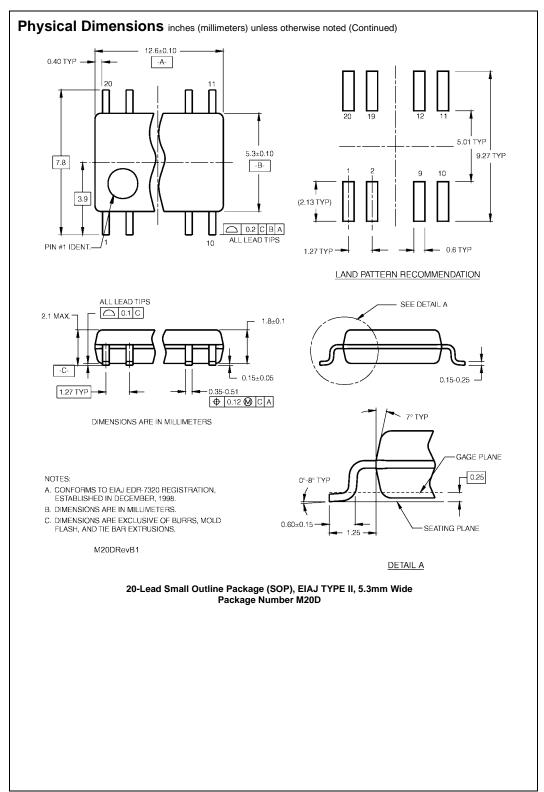
AC Electrical Characteristics

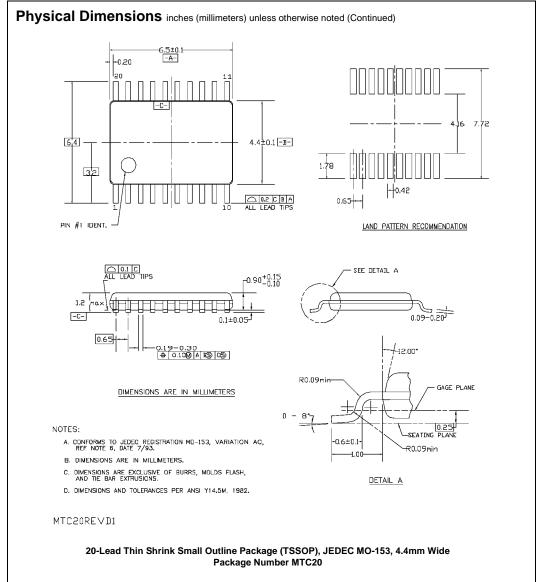
 V_{CC} = 2.0V to 6.0V, C_L = 50 pF, $t_{\rm f}$ = $t_{\rm f}$ = 6 ns (unless otherwise specified)

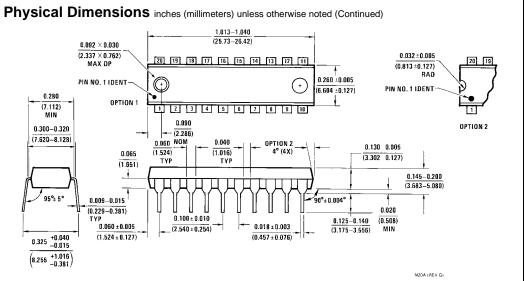
Symbol	Parameter	Conditions	V _{CC}	$T_A = 25^{\circ}C$		T _A = -40 to 85°C	T _A = -55 to 125°C	Units
Syllibol			*CC	Тур		Guaranteed L	imits	Units
t _{PHL} , t _{PLH}	Maximum Propagation	C _L = 50 pF	2.0V	55	100	126	149	ns
	Delay (540)	C _L = 150 pF	2.0V	83	150	190	224	ns
		C _L = 50 pF	4.5V	12	20	25	30	ns
		C _L = 150 pF	4.5V	22	30	38	45	ns
		C _L = 50 pF	6.0V	11	17	21	25	ns
		C _L = 150 pF	6.0V	18	26	32	38	ns
t _{PHL} , t _{PLH}	Maximum Propagation	C _L = 50 pF	2.0V	58	115	145	171	ns
	Delay (541)	C _L = 150 pF	2.0V	83	165	208	246	ns
		C _L = 50 pF	4.5V	14	23	29	34	ns
		C _L = 150 pF	4.5V	17	33	42	49	ns
		C _L = 50 pF	6.0V	11	20	25	29	ns
		C _L = 150 pF	6.0V	14	28	35	42	ns
t _{PZH} , t _{PZL}	Maximum Output Enable	$R_L = 1 k\Omega$						
	Time	C _L = 50 pF	2.0V	75	150	189	224	ns
		C _L = 150 pF	2.0V	100	200	252	298	ns
		C _L = 50 pF	4.5V	15	30	38	45	ns
		C _L = 150 pF	4.5V	30	40	50	60	ns
		C _L = 50 pF	6.0V	13	26	32	38	ns
		C _L = 150 pF	6.0V	17	34	43	51	ns
t _{PHZ} , t _{PLZ}	Maximum Output Disable	$R_L = 1 k\Omega$	2.0V	75	150	189	224	ns
	Time	C _L = 50 pF	4.5V	15	30	38	45	ns
			6.0V	13	26	32	38	ns
t_{THL} , t_{TLH}	Maximum Output Rise	C _L = 50 pF	2.0V	25	60	75	90	ns
	and Fall Time		4.5V	7	12	15	18	ns
			6.0V	6	10	13	15	ns
C _{PD}	Power Dissipation	$\overline{G} = V_{IH}$		10				pF
· =	Capacitance (Note 5)	G = V _{IL}		50				pF
C _{IN}	Maximum Input			5	10	10	10	pF
	Capacitance							
C _{OUT}	Maximum Output Capacitance			15	20	20	20	pF
	1				l	1	1	

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC}^2 f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$.









20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N20A

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